

Features

- Low start-up voltage: 0.7V (Typ.), 0.9V (Max.)
- High efficiency: 85% (Typ.), $V_{out} \geq 2.7V$
- High output voltage accuracy: $\pm 2.5\%$
- Output voltage: 1.8V, 2.7V, 3.0V, 3.3V, 3.7V, 5.0V
- Output current up to 100mA
- Ultra low supply current I_{DD2} : 4 μ A (Typ.)
- Low ripple and low noise
- Low shutdown current: 0.5 μ A (Typ.)
- TO92, SOT89, SOT23 and SOT23-5 package

Applications

- Palmtops/PDAs
- Portable communicators/Smartphones
- Cameras/Camcorders
- Battery-powered equipment

General Description

The HT77XX series is a set of PFM step-up DC/DC converter with high efficiency and low ripple. The series features extremely low start-up voltage and high output voltage accuracy. They require only three external components to provide a fixed output voltage of 1.8V, 2.7V, 3.0V, 3.3V, 3.7V or 5.0V. CMOS technology ensures ultra low supply current and makes them ideal for battery-operated applications powered from one or more cells.

The HT77XX consists of an oscillator, a PFM control circuit, a driver transistor, a reference voltage unit, and a high speed comparator. They employ pulse frequency modulation (PFM) for minimum supply current and ripple at light output loading. These devices are available in space saving TO92, SOT89, SOT23 and SOT23-5 packages. For SOT23-5 package, it also build-in a chip enable function to reduce power consumption during shutdown mode.

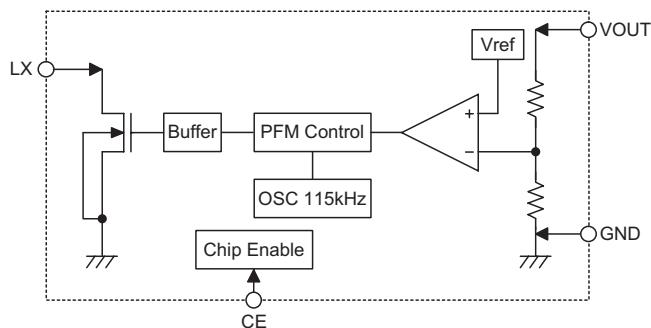
Selection Table

Part No.	Output Voltage	Package	Marking
HT7718	1.8V	TO92 SOT89 SOT23 SOT23-5	HT77XX (for TO92) HT77XX# (for SOT89) 77XX# (for SOT23) 77XX# (for SOT23-5)
HT7727	2.7V		
HT7730	3.0V		
HT7733	3.3V		
HT7737	3.7V		
HT7750	5.0V		

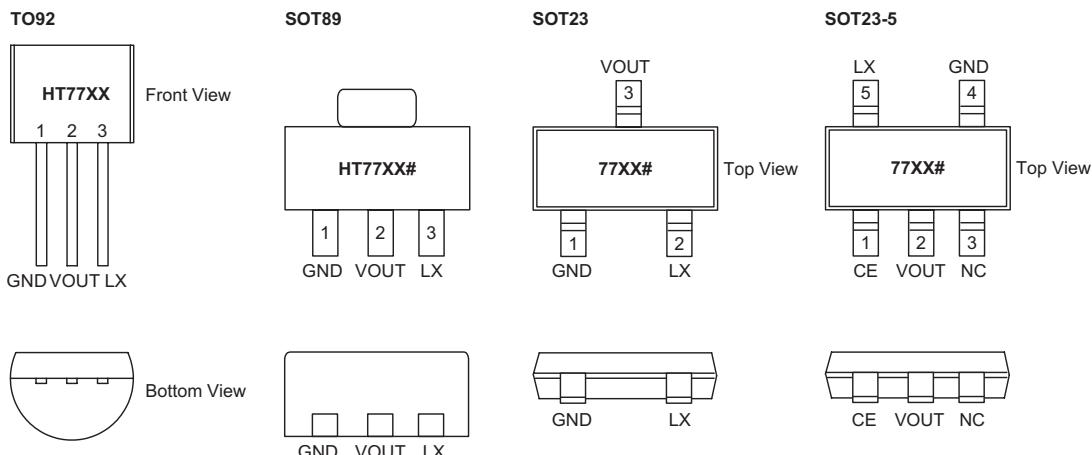
Note: "XX" stands for output voltages.

Only lead free devices are available. "#" stands for lead free devices. For the TO92 package, there will be a "#" mark at the end of the date code.

Block Diagram



Pin Assignment



Pin Description

Pin No.				Pin Name	Description
TO92	SOT89	SOT23	SOT23-5		
—	—	—	1	CE	Chip enable pin, high active
2	2	3	2	VOUT	DC/DC converter output monitoring pin
—	—	—	3	NC	No connection
1	1	1	4	GND	Ground pin
3	3	2	5	LX	Switching pin

Absolute Maximum Ratings

Supply Voltage V_{SS} -0.3V to V_{SS} +7V Storage Temperature -50°C to 125°C
 Operating Temperature -40°C to 85°C

Note: These are stress ratings only. Stresses exceeding the range specified under "Absolute Maximum Ratings" may cause substantial damage to the device. Functional operation of this device at other conditions beyond those listed in the specification is not implied and prolonged exposure to extreme conditions may affect device reliability.

Thermal Information

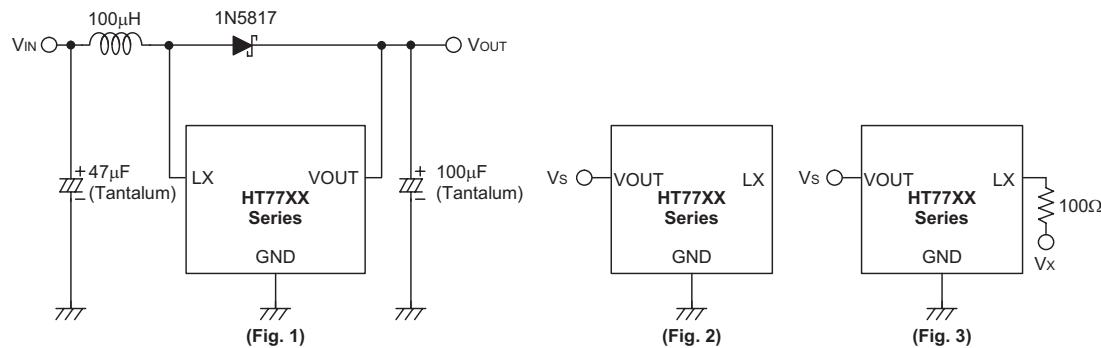
Symbol	Parameter	Package	Max.	Unit
θ_{JA}	Thermal Resistance (Junction to Ambient) (Assume no ambient airflow, no heat sink)	SOT89	300	°C/W
		TO92	300	°C/W
		SOT23	330	°C/W
		SOT23-5	320	°C/W
P_D	Power Dissipation	SOT89	0.33	W
		TO92	0.33	W
		SOT23	0.3	W
		SOT23-5	0.31	W

Note: P_D is measured at $T_a = 25^\circ\text{C}$

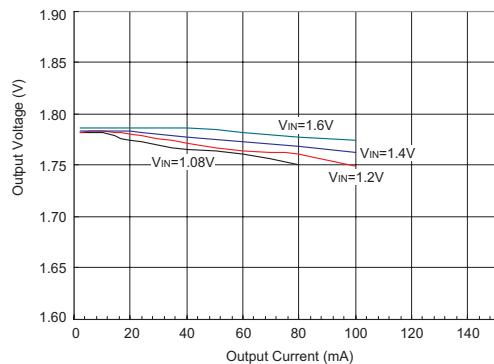
Electrical Characteristics
 $V_{IN}=V_{OUT} \times 0.6$; $I_{OUT}=10\text{mA}$; $T_a=25^\circ\text{C}$ (Unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
V_{IN}	Input Voltage	—	—	—	6	V
ΔV_{OUT}	Output Voltage Tolerance	—	-2.5	—	2.5	%
V_{START}	Start-up Voltage (Fig. 1)	$V_{IN}: 0 \rightarrow 2\text{V}$; $I_{OUT}=1\text{mA}$	—	0.7	0.9	V
V_{HOLD}	Minimum Hold-on Voltage (Fig. 1)	$V_{IN}: 2 \rightarrow 0\text{V}$; $I_{OUT}=1\text{mA}$	—	—	0.7	V
I_{IN}	No-load Input Current (Fig. 1)	$I_{OUT}=0\text{mA}$	—	10	20	μA
I_{DD1}	Supply Current 1 (Fig. 2)	$V_S=V_{OUT} \times 0.95$ Measured at V_{OUT} pin	$V_{OUT}=1.8\text{V}$	—	35	50
			$V_{OUT}=2.7\text{V}$	—	40	60
			$V_{OUT}=3.0\text{V}$	—	45	68
			$V_{OUT}=3.3\text{V}$	—	55	81
			$V_{OUT}=3.7\text{V}$	—	64	85
			$V_{OUT}=5.0\text{V}$	—	85	134
I_{DD2}	Supply Current 2 (Fig. 2)	$V_S=V_{OUT}+0.5\text{V}$ Measured at V_{OUT} pin	—	4	7	μA
I_{SHDN}	Shutdown Current	$CE=GND$	—	0.5	1	μA
V_{IH}	CE High Threshold	—	2	—	—	V
V_{IL}	CE Low Threshold	—	—	—	0.4	V
I_{LEAK}	LX Leakage Current (Fig. 3)	$V_S=V_{OUT}+0.5\text{V}$, $V_X=6\text{V}$ Measured at the LX pin	—	—	0.9	μA
f_{OSC}	Maximum Oscillator Frequency (Fig. 3)	$V_S=V_{OUT} \times 0.95$ Measured at LX pin	—	115	—	kHz
D_{OSC}	Oscillator Duty Cycle (Fig. 3)	$V_S=V_{OUT} \times 0.95$ Measured at LX pin	65	75	85	%
η	Efficiency	$V_{OUT} \leq 1.8\text{V}$	—	80	—	%
		$V_{OUT} \geq 2.7\text{V}$	—	85	—	

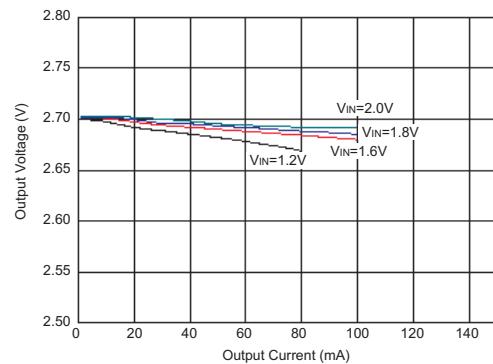
Note: Absolute maximum ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but do not guarantee specific performance limits. The guaranteed specifications apply only for the test conditions listed.

Test Circuit


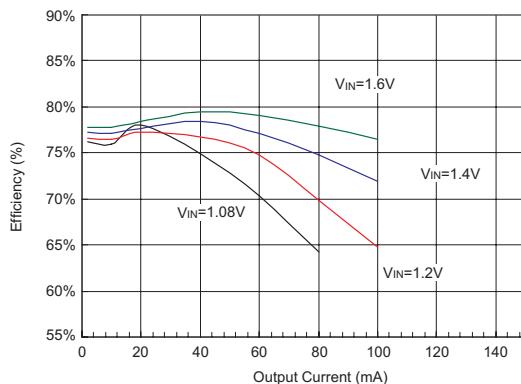
Typical Performance Characteristics



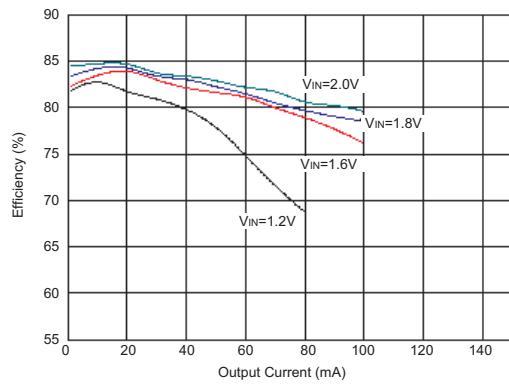
HT7718 Output Voltage v.s Output Current



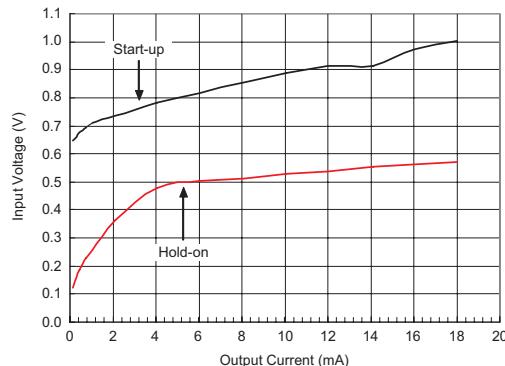
HT7727 Output Voltage v.s Output Current



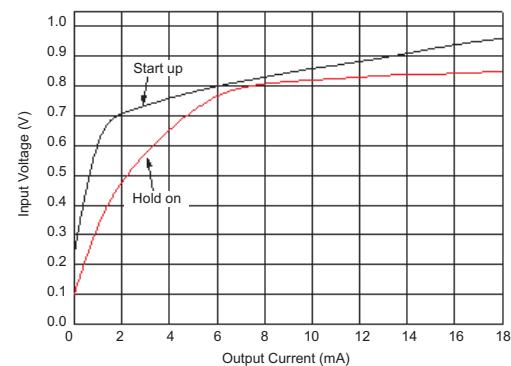
HT7718 Efficiency v.s Output Current



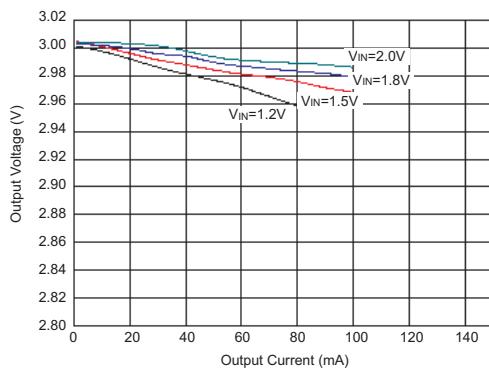
HT7727 Efficiency v.s Output Current



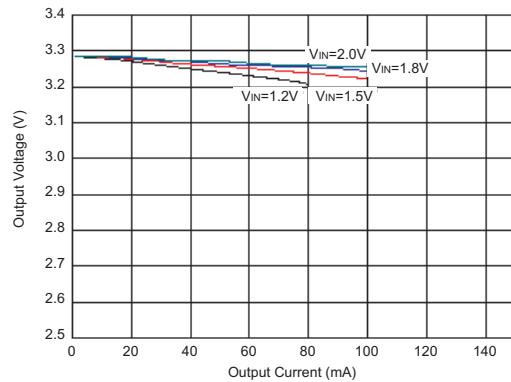
HT7718 Start-Up& Hold-On Voltage



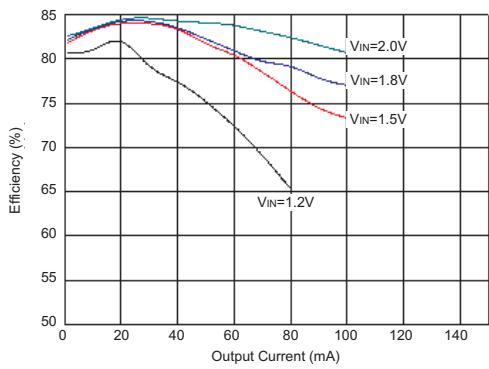
HT7727 Start-Up& Hold-On Voltage



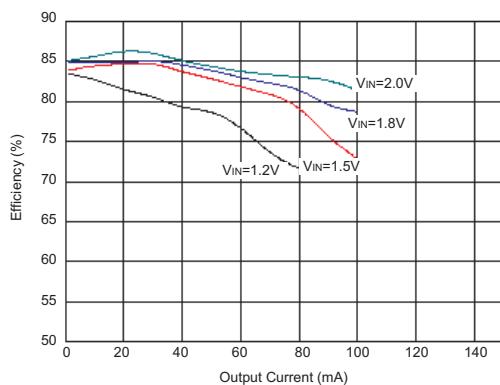
HT7730 Output Voltage v.s Output Current



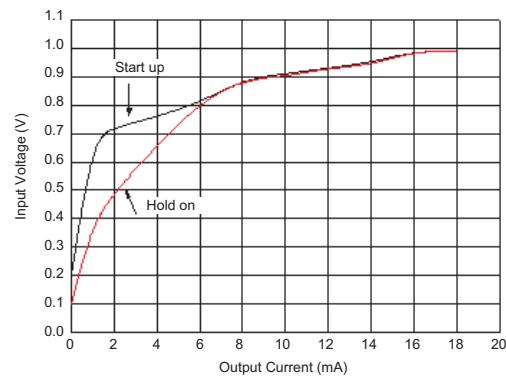
HT7733 Output Voltage v.s Output Current



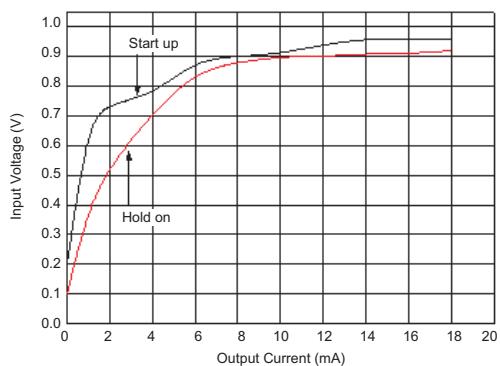
HT7730 Efficiency v.s Output Current



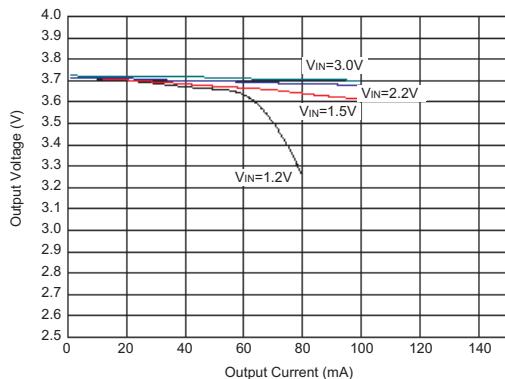
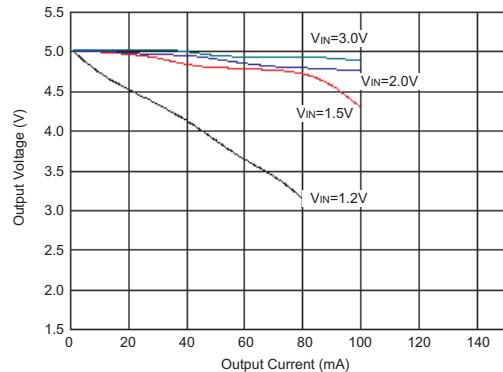
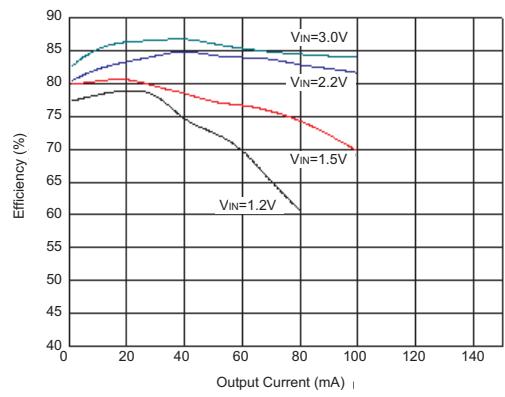
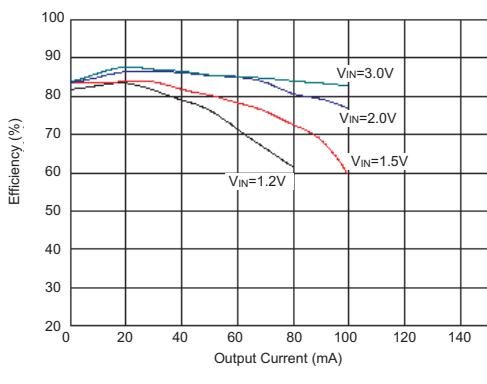
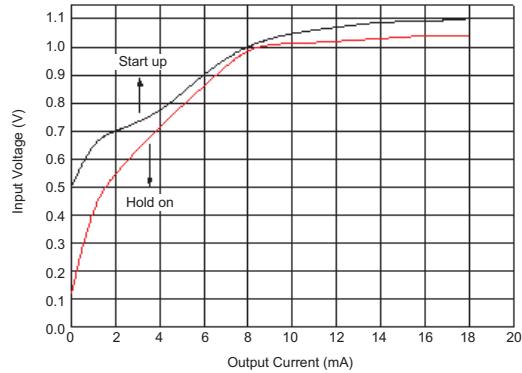
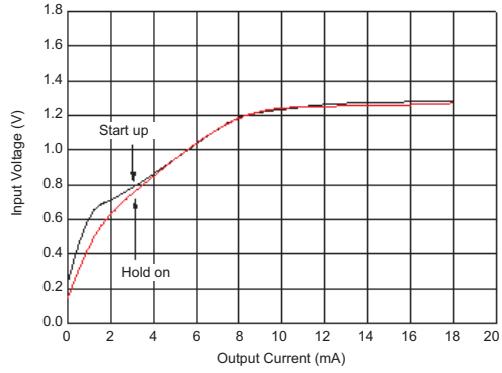
HT7733 Efficiency v.s Output Current

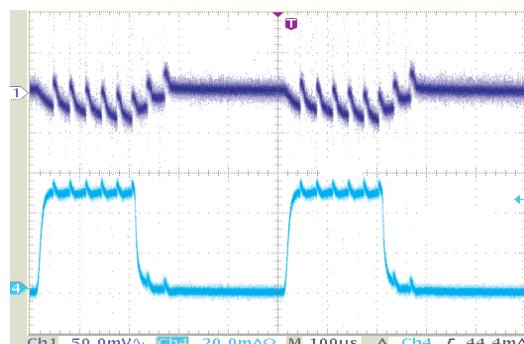
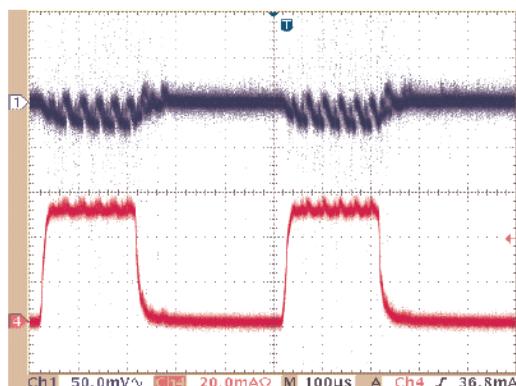
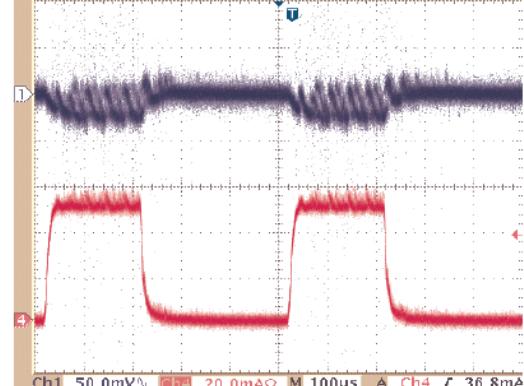
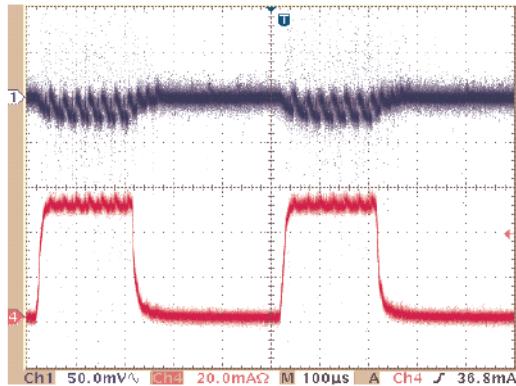
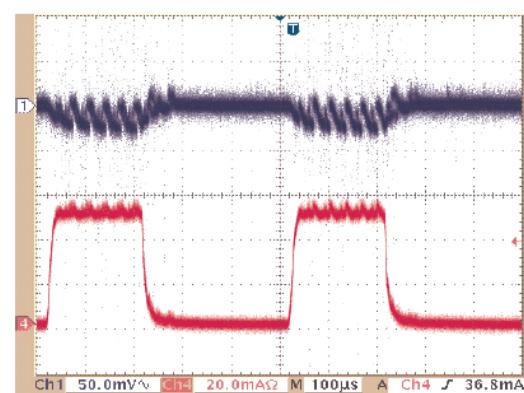
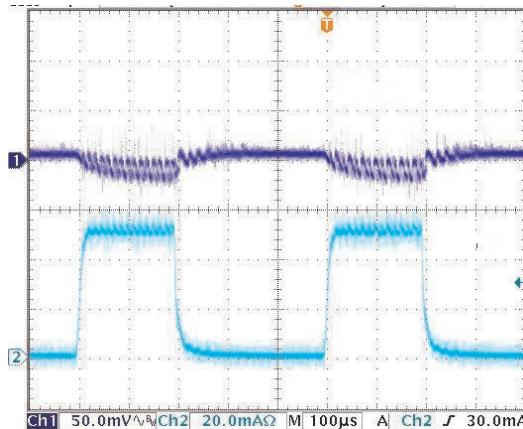


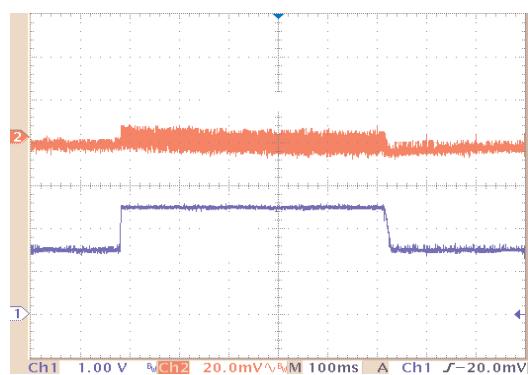
HT7730 Start-Up& Hold-On Voltage



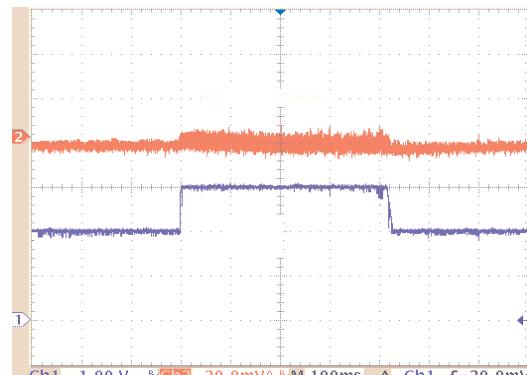
HT7733 Start-Up& Hold-On Voltage


HT7737 Output Voltage v.s Output Current

HT7750 Output Voltage v.s Output Current

HT7737 Efficiency v.s Output Current

HT7750 Efficiency v.s Output Current

HT7737 Start-Up& Hold-On Voltage

HT7750 Start-Up& Hold-On Voltage





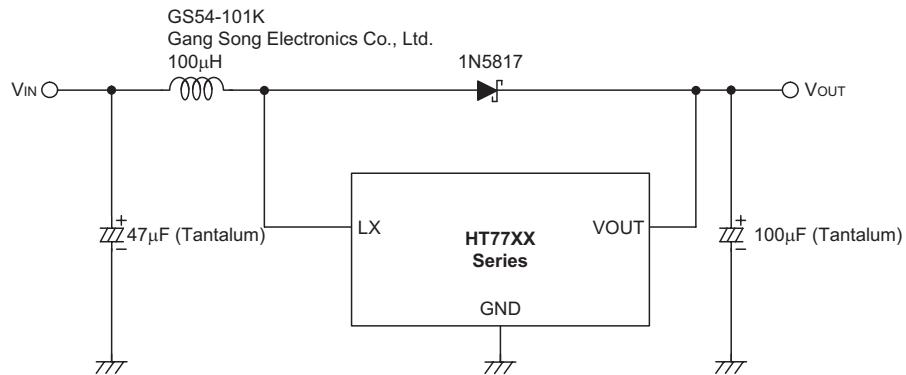
HT7733 Line Transient Response
($L=100\mu H$, $C_{OUT}=100\mu F$)



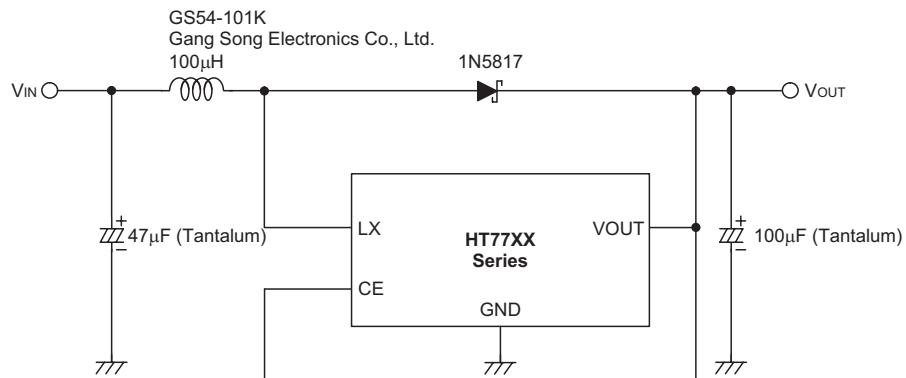
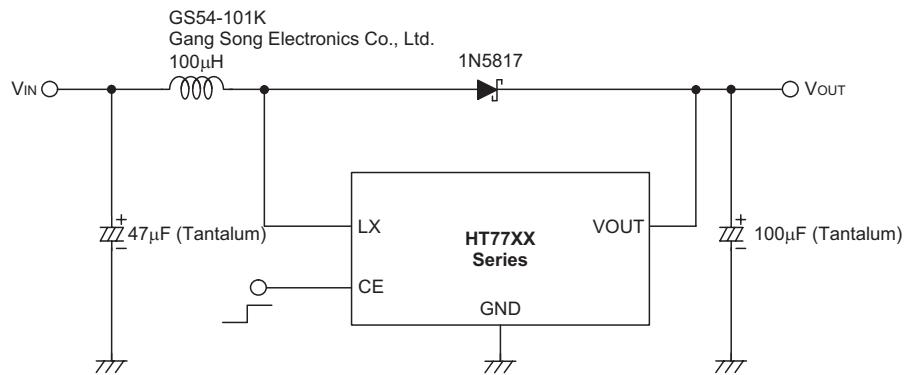
HT7750 Line Transient Response
($L=100\mu H$, $C_{OUT}=100\mu F$)

Application Circuits

Without CE Pin



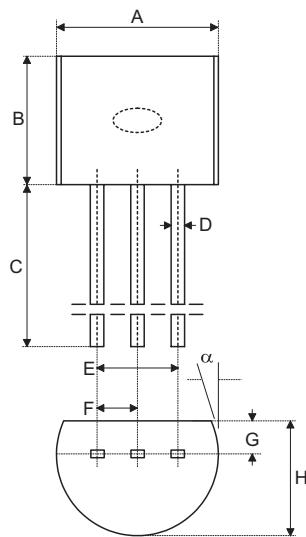
With CE Pin



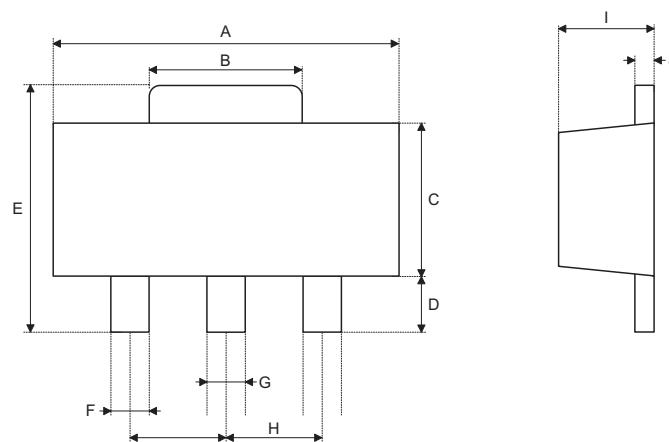
Note: For the SOT23-5 package, when CE is pulled low, the internal blocks of the device, such as the reference band gap, gain block, and all feedback and control circuitry will be switched off. The boost converter's output, V_{OUT}, will be at a value one Schottky diode voltage drop below the input voltage and the LX pin remains in a high impedance condition. The output capacitor and load at V_{OUT} determine the rate at which V_{OUT} decays.

Package Information

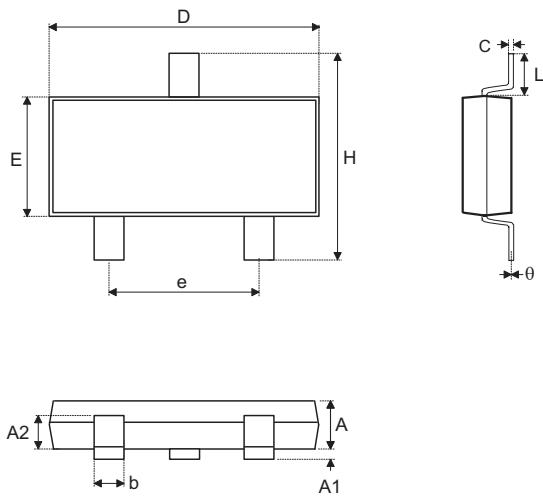
3-pin TO92 Outline Dimensions



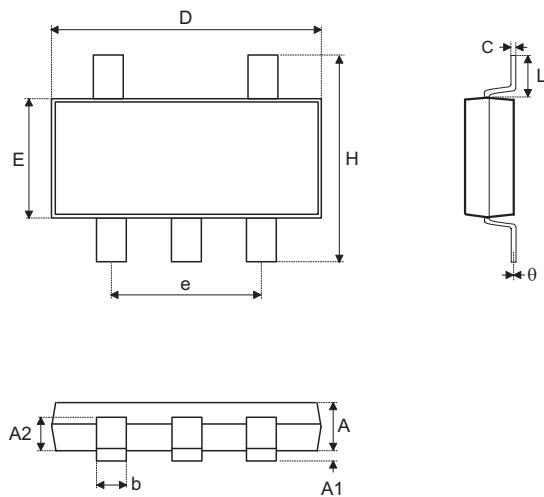
Symbol	Dimensions in mil		
	Min.	Nom.	Max.
A	170	—	200
B	170	—	200
C	500	—	—
D	11	—	20
E	90	—	110
F	45	—	55
G	45	—	65
H	130	—	160
I	8	—	18
α	4°	—	6°

3-pin SOT89 Outline Dimensions


Symbol	Dimensions in mil		
	Min.	Nom.	Max.
A	173	—	181
B	59	—	72
C	90	—	102
D	35	—	47
E	155	—	167
F	14	—	19
G	17	—	22
H	—	59	—
I	55	—	63
J	14	—	17

3-pin SOT23 Outline Dimensions


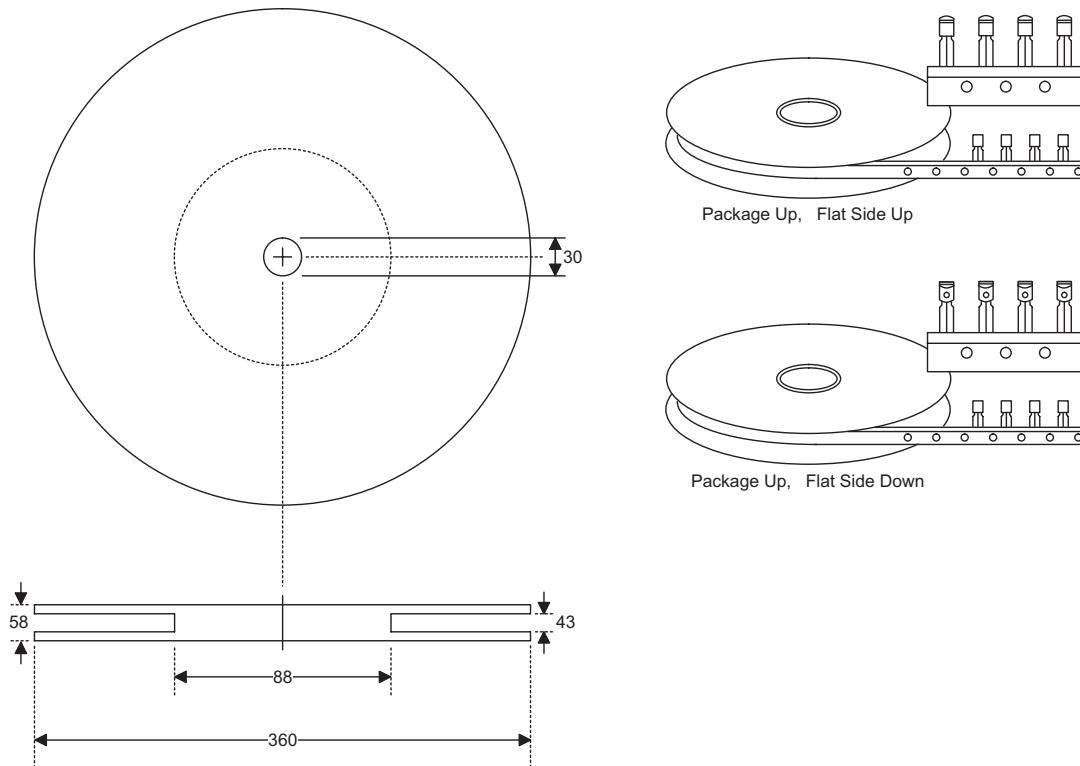
Symbol	Dimensions in mm		
	Min.	Nom.	Max.
A	1.0	—	1.3
A1	—	—	0.1
A2	0.7	—	0.9
b	0.35	—	0.50
C	0.10	—	0.25
D	2.7	—	3.1
E	1.4	—	1.8
e	—	1.9	—
H	2.6	—	3.0
L	0.37	—	—
θ	1°	—	9°

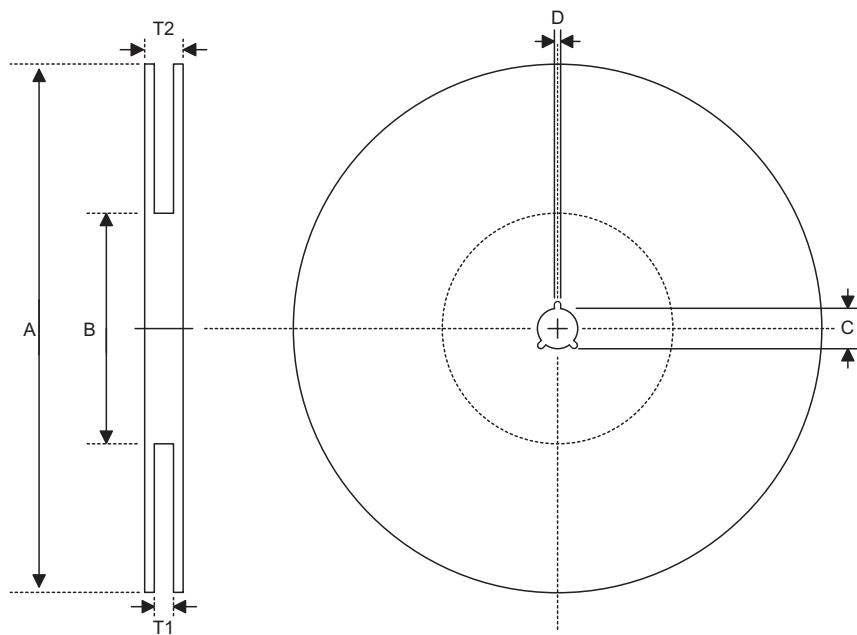
5-pin SOT23-5 Outline Dimensions


Symbol	Dimensions in mm		
	Min.	Nom.	Max.
A	1.0	—	1.3
A1	—	—	0.1
A2	0.7	—	0.9
b	0.35	—	0.50
C	0.10	—	0.25
D	2.7	—	3.1
E	1.4	—	1.8
e	—	1.9	—
H	2.6	—	3.0
L	0.37	—	—
θ	1°	—	9°

Product Tape and Reel Specifications

TO92 Reel Dimensions (Unit: mm)

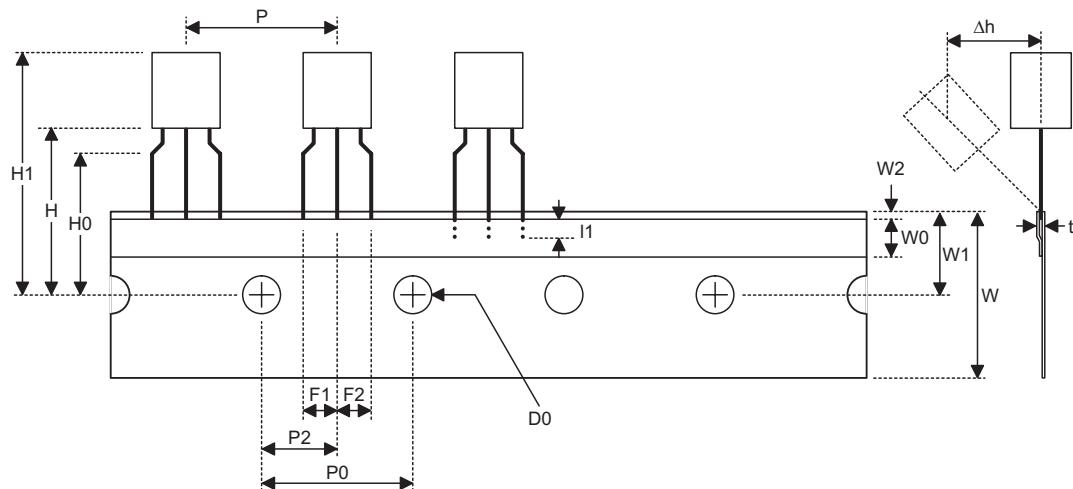


Reel Dimensions

SOT89

Symbol	Description	Dimensions in mm
A	Reel Outer Diameter	180.0±1.0
B	Reel Inner Diameter	62.0±1.5
C	Spindle Hole Diameter	12.75 ^{+0.15/-0.00}
D	Key Slit Width	1.90±0.15
T1	Space Between Flange	12.4 ^{+0.2/-0.0}
T2	Reel Thickness	17.0 ^{+0.0/-0.4}

SOT23, SOT23-5

Symbol	Description	Dimensions in mm
A	Reel Outer Diameter	178.0±1.0
B	Reel Inner Diameter	62.0±1.0
C	Spindle Hole Diameter	13.0±0.2
D	Key Slit Width	2.50±0.25
T1	Space Between Flange	8.4 ^{+1.5/-0.0}
T2	Reel Thickness	11.4 ^{+1.5/-0.0}

Carrier Tape Dimensions


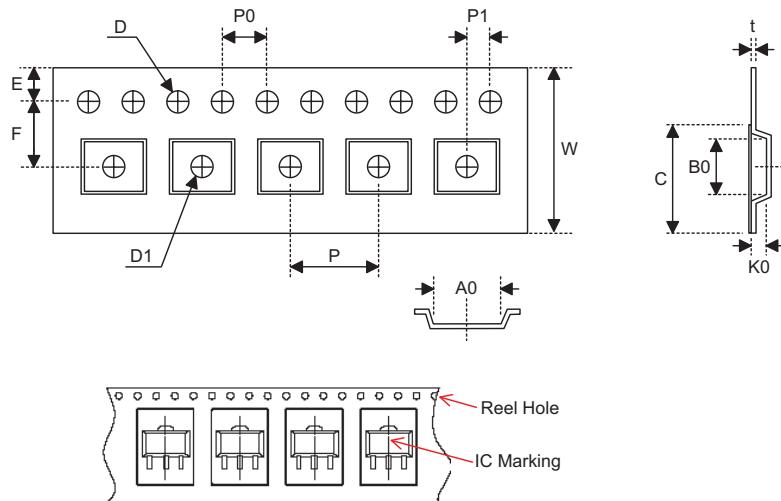
TO92

Symbol	Description	Dimensions in mm
I_1	Taped Lead Length	(2.5)
P	Component Pitch	12.7 ± 1.0
P_0	Perforation Pitch	12.7 ± 0.3
P_2	Component to Perforation (Length Direction)	6.35 ± 0.40
F_1	Lead Spread	$2.5^{+0.4/-0.1}$
F_2	Lead Spread	$2.5^{+0.4/-0.1}$
Δh	Component Alignment	0.0 ± 0.1
W	Carrier Tape Width	$18.0^{+1.0/-0.5}$
W_0	Hold-down Tape Width	6.0 ± 0.5
W_1	Perforation Position	9.0 ± 0.5
W_2	Hold-down Tape Position	(0.5)
H_0	Lead Clinch Height	16.0 ± 0.5
H_1	Component Height	Less than 24.7
D_0	Perforation Diameter	4.0 ± 0.2
t	Taped Lead Thickness	0.7 ± 0.2
H	Component Base Height	19.0 ± 0.5

Note: Thickness less than 0.38 ± 0.05 mm~0.5mm

P0 Accumulated pitch tolerance: ± 1 mm/20pitches.

() Bracketed figures are for reference only.

Carrier Tape Dimensions

SOT89

Symbol	Description	Dimensions in mm
W	Carrier Tape Width	$12.0^{+0.3/-0.1}$
P	Cavity Pitch	8.0 ± 0.1
E	Perforation Position	1.75 ± 0.10
F	Cavity to Perforation (Width Direction)	5.50 ± 0.05
D	Perforation Diameter	$1.5^{+0.1/-0.0}$
D1	Cavity Hole Diameter	$1.5^{+0.1/-0.0}$
P0	Perforation Pitch	4.0 ± 0.1
P1	Cavity to Perforation (Length Direction)	2.0 ± 0.1
A0	Cavity Length	4.8 ± 0.1
B0	Cavity Width	4.5 ± 0.1
K0	Cavity Depth	1.8 ± 0.1
t	Carrier Tape Thickness	0.300 ± 0.013
C	Cover Tape Width	9.3 ± 0.1

SOT23, SOT23-5

Symbol	Description	Dimensions in mm
W	Carrier Tape Width	8.0 ± 0.3
P	Cavity Pitch	4.0 ± 0.1
E	Perforation Position	1.75 ± 0.10
F	Cavity to Perforation (Width Direction)	3.50 ± 0.05
D	Perforation Diameter	$1.5^{+0.1/-0.0}$
D1	Cavity Hole Diameter	$1.5^{+0.1/-0.0}$
P0	Perforation Pitch	4.0 ± 0.1
P1	Cavity to Perforation (Length Direction)	2.00 ± 0.05
A0	Cavity Length	3.15 ± 0.10
B0	Cavity Width	3.2 ± 0.1
K0	Cavity Depth	1.4 ± 0.1
t	Carrier Tape Thickness	0.20 ± 0.03
C	Cover Tape Width	5.3 ± 0.1

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